Interplay between disorder-induced scattering and local field effects in photonic crystal waveguides

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We introduce a theory to describe disorder-induced scattering in photonic crystal waveguides, specifically addressing the influence of local field effects and scattering within high-index-contrast perturbations. Local field effects are shown to increase the predicted disorder-induced scattering loss and result in significant resonance shifts of the propagating waveguide mode. Performing an incoherent averaging calculation, we demonstrate that two types of frequency shifts can be expected, a mean frequency shift and a rms frequency shift both acting in concert to blueshift and broaden the nominal band structure. The disorder-induced broadening is found to increase as the propagation frequency approaches the slow-light regime (mode edge) due to restructuring of the electric-field distribution. These findings shed new light on why it has hitherto been impossible to observe the very slow-light regime for photonic-crystal waveguides and suggest that the nominal slow-light mode edge may not even exist.

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I. INTRODUCTION

Photonic crystal (PC) structures comprised of high-indexcontrast cavities and waveguides offer a rich degree of control over light-matter interactions, leading to trapped¹ and slow-light modes² buried within a forbidden photonic band gap. In the more practical, planar PC semiconductor systems, waveguide modes can be completely bound below the light line. However, manufacturing imperfections result in *fabrication disorder* that breaks the translational invariance of a nominally perfect lattice and causes external scattering of the bound modes. From a theoretical perspective, the role and impact of fabrication disorder on slow-light slab waveguides is becoming better understood: $3-5$ $3-5$ minute sidewall imperfections act to perturb the propagating mode causing the light to out scatter through radiation modes or backscatter and multiple scatter within the waveguide. $6-8$ $6-8$ Scattering losses become particularly pronounced in the slow-light regime as the local density of states of the mode into which light can scatter increases.

Although many experiments have confirmed this slowlight loss behavior, $9-11$ an open question that still remains is what is the effect of disorder on the photonic band structure? The answer to this question involves a complex interplay between local-field corrections and enforcing boundary conditions between parallel and perpendicular field components. Experimental evidence for a dramatic reduction in transmission near the mode edge is observed to take place much sooner than that predicted for the scaling of scattering loss. This suggests that some unknown effect is either shifting the mode edge or broadening the band structure. Here we address this question directly and show that surprisingly large changes in the band structure occur which have not been anticipated before. Our findings introduce a fresh understanding of the role of disorder-induced scattering and apply to a wide range of high-index-contrast structures including coupled resonator optical waveguides (CROWs).

The usual theoretical approaches to modeling disorderinduced scattering employ standard perturbation theory where the modal electric field is used with the dielectric index change to model polarization scatterers, through P_{dis} $=\Delta \varepsilon \mathbf{E}_0$, with \mathbf{E}_0 the unperturbed field and $\Delta \varepsilon$ is the dielectric contrast change resulting from a spatial perturbation (e.g., air to silicon gives $\Delta \varepsilon \approx 12$ $\Delta \varepsilon \approx 12$.¹² For high-index-contrast perturbations, as shown by Johnson *et al.*, [13](#page-4-10) this polarization scatterer is problematic for several reasons: (i) the parallel components of the electric field and the perpendicular components of the displacement field must be continuous across the surface and (ii) the index change results in local-field corrections. Andreani and Gerace¹⁴ attempted to estimate the magnitude of this error in their theory by comparing with a simple numerical-supercell calculation of perfect hole shapes with different radii and they concluded that the effects of local fields was not important. Wang *et al.*[15](#page-4-12) employed the well-known *slowly varying surface approximation*, [13](#page-4-10) valid *only* for smooth bumps, and demonstrated the impact on increasing the scattering losses. For PC cavity systems, Ramunno and Hughes¹⁶ showed that a *quickly varying surface perturbation* can cause mean resonance shifts of a strongly confined cavity mode.¹⁶ The rms ensemble-average shifts were computed for intrinsically lossy CROW structures, $17,18$ $17,18$ but local fields were not considered and only band-edge broadening was predicted.

With regards to PC waveguides, to the authors' knowledge, there have been no calculations nor any awareness of disorder-induced resonance shifts. Neither has anyone computed disorder-induced losses in the presence of realistic rapidly varying surface perturbation by properly addressing the two problematic criteria above. In this work, we overcome these limitations, and introduce a straightforward opticalscattering theory that allows one to compute scattering losses and resonance shifts within an ensemble-averaging procedure while accounting for local field effects. The *ensemble*average statistical calculation applies to measurements of an ensemble of nominally identical structures and (or) it applies to the statistics of one waveguide which contains many nominally identical unit cells. This is a reasonable first model to report since typical PC waveguides of only 1 mm length contain already many thousands of unit cells; our methodology can also help guide future coherent-scattering theories, where such effects were neglected.⁷ Using representative calculations, we subsequently demonstrate that significant and unusual disorder-induced changes in the band structure can occur, as well as modifications (increases) to the predicted scattering losses.

II. THEORY AND CALCULATIONS

The total electric field, in the presence of disorder can be calculated from

$$
\mathbf{E}(\mathbf{r};\omega) = \mathbf{E}_i(\mathbf{r};\omega) + \int_{\text{all space}} d\mathbf{r}' \overline{\mathbf{G}}(\mathbf{r}, \mathbf{r}';\omega) \cdot \mathbf{P}(\mathbf{r}';\omega),
$$
\n(1)

where $P(\mathbf{r}'; \omega)$ is the polarizationlike density due to the disorder in the system, $\mathbf{E}_i(\mathbf{r}; \omega)$ is the electric field in the ideal (no disorder) system,¹² and $\overline{G}(r, r'; \omega)$ is the photon Green's function. The Green's function is simply a dipole solution to the Maxwell wave equation and it contains information about how light scatters as well as the local-photon density of states. For convenience, we partition the Green's function into contributions from the bound waveguide mode, radiation modes above the light line, and other modes as $\vec{G}(\mathbf{r}, \mathbf{r}'; \omega) = \vec{G}_B(\mathbf{r}, \mathbf{r}'; \omega) + \vec{G}_R(\mathbf{r}, \mathbf{r}'; \omega) + \vec{G}_O(\mathbf{r}, \mathbf{r}'; \omega)$. The bound mode Green's function is given analytically from properties of the bound mode^{3,[19](#page-4-17)}

$$
\overline{\mathbf{G}}_{\mathbf{B}}(\mathbf{r}, \mathbf{r}'; \omega) = i \frac{a \omega}{2v_g} [\mathbf{e}_k(\mathbf{r}) \otimes \mathbf{e}_k^*(\mathbf{r}') e^{ik(x-x')} \Theta(x-x')
$$

$$
+ \mathbf{e}_k^*(\mathbf{r}) \otimes \mathbf{e}_k(\mathbf{r}') e^{ik(x'-x)} \Theta(x'-x)], \qquad (2)
$$

where v_g is the group velocity (assumed to be positive), $\mathbf{e}_k(\mathbf{r})$ is the Bloch mode electric field normalized by $\int_{\text{unit cell}} d\mathbf{r} \varepsilon(\mathbf{r}) |\mathbf{e}_k(\mathbf{r})|^2 = 1$, \otimes is a tensor product, $\mathbf{e}_{-k}(\mathbf{r})$ $=$ **e** $\mathbf{e}_k^*(\mathbf{r})$, and $\Theta(x)$ is the Heaviside step function. For our calculations below, we use a W1 PC waveguide formed from a semiconductor membrane by omitting a row of holes in a two-dimensional triangular array of holes. The lattice pitch is $a = 480$ nm, the hole radius $r = 95$ nm, and the slab thickness is *h*= 160 nm. The dispersion of the *ideal* waveguide mode is shown in Fig. $1(a)$ $1(a)$. The electric-field Bloch mode distribution is shown on symmetry planes in the unit cell in Fig. $1(b)$ $1(b)$ for a wave vector near the mode edge.

The disorder fluctuations of interest must closely correspond to real images of fabricated PC waveguides 20 and thus we consider disorder in PC slab structures that is dominated by perturbations of the perimeter of the holes, an example of which is shown in Fig. $1(c)$ $1(c)$; this is also consistent with previous models used to successfully fit experiments. $6,9$ $6,9$ We take the radial perturbation Δr to be a Gaussian random variable with a mean of zero and a standard deviation of σ . Two radial perturbations are correlated by $\langle \Delta r(\phi_i) \Delta r(\phi'_j) \rangle$ $=\sigma^2 e^{-r|\phi_i-\phi'_j|/l_p}\delta_{i,j}$, where the subscript indexes the holes, ϕ_i is the angular position of the point measured about the center of the hole, r is the hole radius, and l_p is the correlation

FIG. 1. (Color online) (a) Nominal dispersion of PC waveguide mode (blue/lowest solid) and the broadened disorder-induced band structure that we will introduce later (gray shading). (b) Electricfield Bloch mode near the band edge along symmetry planes in the unit cell. (c) Example of a disordered hole profile that satisfies the statistics used in the calculation (blue jagged). The ideal radius (dashed black) and correlation length (short red arc) are shown for reference, where *R* indicates the nominal radius of the unperturbed hole and σ is the rms fluctuation.

length measured around the circumference. The change in dielectric constant can be written as $\Delta \varepsilon(\mathbf{r}) = (\varepsilon_2)$ $-e_1\Delta r \delta(\sqrt{x_i^2+y_i^2}-r)\Theta(h/2-|z|)$, where x_i and y_i are the components of **r** measured from the center of the hole, and the Heaviside step function restricts the disorder to a slab of thickness *h*. In this analysis, below, we used representative disorder parameters of $\sigma = 3$ nm and $l_p = 40$ nm, which are typical for fabricated samples.

The failure of the weak contrast model, namely, P_{dis} $=\Delta \varepsilon \mathbf{E}_0$ is most obvious by considering a small dielectric sphere introduced in a homogeneous background with dielectric constant ε_2 . It is well known that the weak contrast polarizability $\Delta \varepsilon$ must be replaced with the correct polarizability $3\Delta\varepsilon/(3\varepsilon_2 + \Delta\varepsilon)$ [as can easily be proven from Eq. ([1](#page-1-1)) $(Ref. 16)$ $(Ref. 16)$ $(Ref. 16)$]. Due to local field effects, the macroscopic scattering depends on the microscopic geometry of the scatter and this is also true for disordered waveguides. This issue has been partly investigated by Johnson *et al.*, [13](#page-4-10) who give the corrected disorder polarization density due to a disorder element at **r**' as (ω is implicit)

$$
\mathbf{P}(\mathbf{r}) = \left[\frac{\varepsilon_1 + \varepsilon_2}{2} \alpha_{\parallel} \mathbf{E}_{\parallel}(\mathbf{r}) + \varepsilon(\mathbf{r}) \gamma_{\perp} \mathbf{D}_{\perp}(\mathbf{r})\right] \Delta V \delta(\mathbf{r} - \mathbf{r}'),\tag{3}
$$

where α_{\parallel} and γ_{\perp} are polarizabilities for the disorder element, $\varepsilon(\mathbf{r})$ takes a different value depending on which side of the

interface \mathbf{r}' is located, and ΔV is the volume of the disorder element. Due to the $\varepsilon(\mathbf{r})$ factor, $\mathbf{E}^*(\mathbf{r}) \cdot \mathbf{P}(\mathbf{r})$ will have terms proportional to $|\mathbf{E}_{\parallel}(\mathbf{r})|^2$ and $|\mathbf{D}_{\perp}(\mathbf{r})|^2$ and these fields are well defined at a dielectric interface. This improved disorder model hides a great deal of complexity in the polarizabilities α_{\parallel} and γ_{\perp} . The polarizabilities are different for a positive bump (ε_1 extending into ε_2 , $\alpha_{\parallel} = \alpha_{\parallel}^+$) and a negative bump (α_{\parallel}) . Further, in general, the polarizabilities are asymmetric so that $\alpha_{\parallel}^+ \neq -\alpha_{\parallel}^-$. Finally, the exact polarizabilities depend on the precise geometry of the disorder element and must be calculated numerically. It is thus no surprise that only a single isolated bump was treated in Ref. [13.](#page-4-10)

One method to simplify the treatment of the polarizabilities is to assume a structure for the disorder where the polarizability is known. In Ref. [15,](#page-4-12) a polarization density of the form $P(r) = \Delta \varepsilon(r) [E_{\parallel}(r) + \varepsilon(r) \frac{D_{\perp}(r)}{\varepsilon_1 \varepsilon_2}] \delta(r - r')$ was used, namely, the slowly-varying surface approximation. This takes care of the issue of the $E(r)$ being ill defined at the interface but it has some subtle and questionable assumptions. Implicit in the derivation of this term is the assumption that the disordered surface is smooth; effectively that the hole radius changes but remains nearly circular. As a model for the disorder in real fabricated samples, this is rather suspect, and it is known that the interface fluctuations vary rapidly [cf. Fig. $1(c)$ $1(c)$ and Ref. [20](#page-4-18)]. Our solution to this general problem is to use a representative model for the polarizabil-ity, namely, Eq. ([3](#page-1-2)) with the numerically calculated polarizabilities for a cylindrical bump, 13 in combination with our numerically generated disordered profile.

It is easiest to compare these polarization-density models above using our incoherent-scattering calculation where the band-edge resonances are suppressed. The incoherent average power loss, which is dominated by backscatter loss for slow-light PC waveguides, is 3

$$
\langle \alpha_{\text{back}} \rangle = \left(\frac{a\omega}{2v_g}\right)^2 \int \int d\mathbf{r} d\mathbf{r}' \langle [\mathbf{E}(\mathbf{r}) \cdot \mathbf{P}(\mathbf{r})] [\mathbf{E}^*(\mathbf{r}') \cdot \mathbf{P}^*(\mathbf{r}')] \rangle, \tag{4}
$$

where the integration is performed over a single unit cell and $\mathbf{E}(\mathbf{r}) = \mathbf{e}_k(\mathbf{r})e^{ikx}$. The incoherent averaged backscatter loss is plotted in Fig. [2](#page-2-0) for the weak-contrast (blue—lower solid), smooth-surface (green—middle solid), and cylindrical-bump (red—upper solid) models. Although the exact loss predictions differ, all the models predict similar loss trends and their magnitudes are similar. For the roughness statistics typical of PC waveguide systems, we find reasonable agreement between the backscatter loss predictions of the three models, though the smooth surface and weak contrast models underestimate the scattering loss.

As discussed previously, one of the effects neglected when one ignores the $\vec{G}_O(\mathbf{r}, \mathbf{r}'; \omega)$ contribution of the Green function is disorder-induced frequency shifts. This hitherto—theoretically unknown phenomenon for PC waveguides is closely related to the selection of a suitable polarization model, as the predicted frequency shift is sensitive to this term. The first-order *mean frequency shift* due to disorder is given $as²¹$

FIG. 2. (Color online) Incoherent averaged back scatter loss for a single unit cell using the weak-contrast (blue—lower solid), smooth-surface (green—middle solid), and cylindrical-bump (red upper solid) polarization-density models. For reference, the group index (magenta, dot dash) is shown on the right scale.

$$
\langle \Delta \omega \rangle = -\frac{\omega}{2} \int d\mathbf{r} \langle \mathbf{E}^* (\mathbf{r}) \cdot \mathbf{P} (\mathbf{r}) \rangle \tag{5}
$$

with $E(r)$ normalized as before. The frequency shift is usually taken to be zero for zero-mean surface perturbations but as shown previously for a PC cavity, 16 correctly treating local field effects yield a nonzero first-order frequency shift. Considering the above polarization densities both the weak contrast and smooth surface models predict $\langle \Delta \omega \rangle = 0$ due to the symmetry in the polarization for positive and negative bumps. The cylindrical bump polarizability predicts a nonzero $\langle \Delta \omega \rangle$ but the details differ from Ref. [16](#page-4-13) (the simpler PC cavity case) due to differing disorder models; moreover, for the waveguide, we are also dealing with a continuous mode rather than a discrete resonance. When using the polarization density of Eq. (3) (3) (3) , care must be taken when evaluating the expectation value since the value of the polarizabilities depends on the direction of the bump. In addition to the mean frequency shift, which in general may or may not be zero, the rms frequency shift $\langle \Delta \omega \rangle_{\text{rms}} = \sqrt{\langle \Delta \omega^2 \rangle}$ is not. It is calculated in a similar way to the corrected backscatter loss, from

$$
\langle \Delta \omega^2 \rangle = \frac{\omega^2}{4} \int \int dr dr' \langle [\mathbf{E}^* (\mathbf{r}) \cdot \mathbf{P} (\mathbf{r})] [\mathbf{E}^* (\mathbf{r}') \cdot \mathbf{P} (\mathbf{r}')] \rangle.
$$
 (6)

We stress that neither of these two frequency shifts have been predicted nor calculated for PC waveguides yet clearly they are important for the analysis of optical scattering phe-nomena in PC waveguides. Figure [3](#page-3-0) plots the mean (dashed) and rms (solid) frequency shifts for the weak-contrast (blue), smooth-surface (green), and cylindrical-bump (red—upper solid) polarization-density models. The weak-contrast and smooth-surface models—*incorrectly*—predict zero-mean frequency shifts and thus are not shown. The disorder-induced frequency shifts are particularly important for understanding experimental transmission spectra. Typically, very near the band edge, there will be an abrupt drop in the transmission

FIG. 3. (Color online) Mean frequency shift (dashed) and rms frequency shift (solid) using the weak-contrast (blue—middle solid), smooth-surface (green-lower solid), and cylindrical-bump (red—upper solid) polarization-density models. Only the cylindrical-bump model has a nonzero-mean frequency shift. For reference, the group index (magenta, dot dash) is shown on the right scale.

associated with a local frequency shift causing the band to be shifted such that the injected frequency is below the new band edge. As can be seen from the rms frequency shifts, this will be an issue regardless of the polarization model but can be exasperated by a nonzero-mean frequency shift. The inset to Fig. $1(a)$ $1(a)$ depicts the computed band structure with disorder²² (gray shaded band), showing that getting too close to the mode edge is actually impossible. Qualitatively, for waveguide-mode frequencies within a few standard deviations of the mode edge (slow-light regime), we expect that somewhere along the waveguide, total reflection will inevitably occur.

III. DISCUSSION

The improved disorder models that we have introduced are directly relevant to a wide range of enhanced light-matter interaction physics that occurs in nanophotonic waveguides. Apart from the consistent observation of a sudden, dramatic reduction in transmission in PC waveguide near the mode edge (underestimated by current theories), we cite two other examples: (i) observation of the enhanced spontaneous emission with single-photon emitters (quantum dots) near the mode edge indeed observe a broadened and substantially reduced density of states than is expected from the disorderfree band structure²³ and (ii) recent work by Morichetti *et al.*[24](#page-4-22) demonstrate that backscattering is also one of the most severe limiting factors in state-of-the art silicon on insulator nanowires, and our conclusions are directly applicable and supportive of these measurements as well: broadening and band-structure restructuring near the mode edge will, inevitably, result in dramatic backscattering.

A few words about the general modeling approach is also in order. As mentioned before, the losses and frequency shifts that we calculate here are obtained by integrating over the volume of a single unit cell. As such they are the expectation values when an infinite ideal waveguide is subject to identical disorder in every unit cell (periodic disorder). This approximate and simple model provides essential insight into the problem at hand, namely, a disordered waveguide formed by concatenating unit cells from different periodically disordered waveguides. When most of the periodically disordered waveguides are likely to be shifted so that the frequency of interest lies in the stop band (i.e., the rms frequency shift is on the order of the detuning from the nominal band edge), the disordered waveguide is expected to not support propagating modes. In addition since there are many different disordered unit cells in a given waveguide and the frequency shifts that we have provided are averages, it is possible that individual unit cells may be shifted into the stop band when, on average, we expect transmission. The presence of such isolated elements does not necessarily imply a complete elimination of transmission. When light is incident on an ideal waveguide in the stop band, the evanescent tail of the mode will reach into the waveguide even though there is no power propagation. If such a waveguide is very short, on the order of the evanescent decay constant, it is possible for the mode to tunnel through the barrier. We thus expect a similar phenomena to occur in disordered waveguides and so it is only when the majority of the unit cells are shifted into the stop band that propagation will be totally suppressed. Finally, although we have specialized this first theoretical study to incoherent averages, our general results can also be used to guide and improve current models that have been used to describe disorder-induced coherent scattering, e.g., see Refs. [6](#page-4-5) and [25,](#page-4-23) which is left to future work.

IV. CONCLUSIONS

In summary, we have described a theory of disorderinduced scattering to include the influence of local field effects and high-index-contrast perturbations. Our calculations are shown to increase the predicted waveguide losses and result in significant and complex disorder-induced resonance shifts. The band-structure broadening [shown in Fig. $1(a)$ $1(a)$] offers important insights into the fabrication limits of slowlight propagation in PC waveguides and should serve as a further warning that propagation modes near the mode edge will have an increasingly better chance of being completely reflected. These predictions are interesting in their own right and are important for the analysis and interpretation of related experiments.

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